

# **Chip Integration Technology Corporation**

Super Low Barrier High Voltage Power Rectifier

#### Main Product Characteristics

I <sub>F(AV)</sub>	10A
$V_{RRM}$	60V
T	150°C
$V_{(Typ)}$	0.57V

#### ■ Features

- Low forward voltage drop.
- Excellent high temperature stability.
- Fast switching capability.
- Suffix "G" indicates Halogen-free part, ex.CSP1060SG-A.
- Lead-free parts meet environmental standards of MIL-STD-19500/228

#### ■ Mechanical data

• Epoxy: UL94-V0 rated flame retardant.

· Case: Molded plastic, TO-277.

 Lead: Solder plated, solderable per MIL-STD-750, Method 2026.

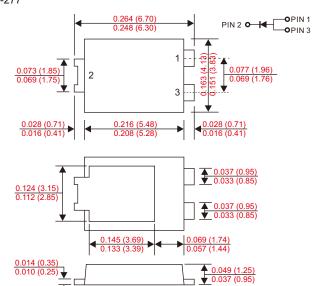
• Polarity: Indicated by cathode band.

• Mounting Position : Any.

• Weight : Approximated 0.093 grams.

### ■ Outline





Dimensions in inches and (millimeters)

### ■ Maximum ratings and electrical characteristics

Rating at  $25^{\circ}$ C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Parameter	Conditions	Symbol	CSP1060S-A		5-A	
rking code			CSP1060S		S	UNIT
Peak repetitive reverse voltage		V <sub>RRM</sub>				
Vorking peak reverse voltage		V <sub>RWM</sub>	60		V	
DC blocking voltage		V <sub>RM</sub>				
Forward rectified current		Io	10			Α
Forward surge current	8.3ms single half sine-wave superimposed on rate load (JEDEC method)	I <sub>FSM</sub>	200			Α
Thermal resistance	Junction to case	R <sub>eJC</sub>	4			°C/W
Operating and Storage temperature		T <sub>J</sub> , T <sub>STG</sub>	-55~+150		°C	
Parameter	Conditions	Symbol	MIN.	TYP.	MAX.	UNIT
Reverse breakdown voltage	I <sub>R</sub> = 0.5mA	V <sub>(BR)R</sub>	60			V
Forward voltage drop	$I_F = 10A, T_J = 25^{\circ}C$	V			700	mV
	I <sub>F</sub> = 10A, T <sub>J</sub> = 125°C	V <sub>F</sub>		570	650	
_	$V_R = V_{RRM} T_J = 25^{\circ}C$				0.5	mA
Reverse current		- I <sub>R</sub>				

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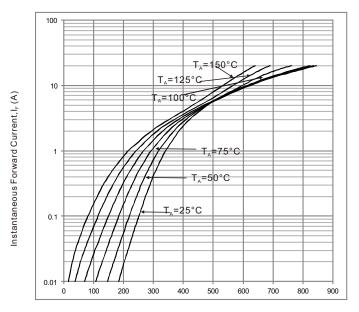
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### ■ Rating and characteristic curves

Fig. 1 - Instantaneous Forward Characteristics



Instantaneous Forward Voltage, V<sub>F</sub> (Volts)

Fig. 2 - Reverse Characteristics

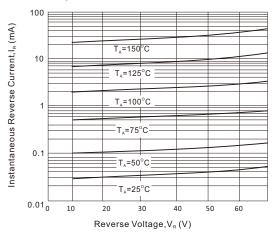


Fig.3 - Forward Current Derating Curve

12
Based on Lead Temp(TL)

8

0
25
50
75
100
125
150
175

Ambient Temperature, TA (°C)

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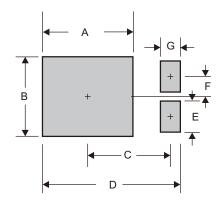
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### ■ TO-277 foot print



Α	В	С	D	Е	F	G
0.185 (4.70)	0.142 (3.60)	0.152 (3.87)	0.260 (6.60)	0.055 (1.40)	0.035 (0.90)	0.031 (0.80)

Dimensions in inches and (millimeters)

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